



## 40V N-CHANNEL ENHANCEMENT MODE MOSFET **POWERDI**

## **Product Summary**

| BV <sub>DSS</sub> | R <sub>DS(ON)</sub> max                        | I <sub>D</sub><br>T <sub>C</sub> = +25°C<br>(Note 9) |
|-------------------|--|--|
| 40V               | $1.8m\Omega$ @ $V_{GS} = 10V$                  | 100A   |
|                   | $3.1 \text{m}\Omega$ @ $V_{GS} = 4.5 \text{V}$ | 100A   |

## **Features**

- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On State Losses
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

## **Description and Applications**

This MOSFET has been designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

PowerDI5060-8 (Type K)

- **Engine Management Systems**
- **Body Control Electronics**
- DC-DC Converters

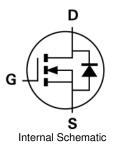
#### **Mechanical Data**

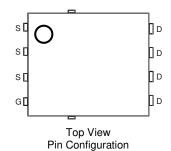
- Case: PowerDI5060-8 (Type K)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)











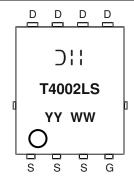
## Ordering Information (Note 4)

| Part Number   | Case                   | Packaging           |
|---------------|------------------------|---------------------|
| DMT4002LPS-13 | PowerDI5060-8 (Type K) | 2,500 / Tape & Reel |

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



T4002LS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 16 = 2016) WW = Week Code (01 to 53)



# **Maximum Ratings** $(@T_A = +25^{\circ}C, \text{ unless otherwise specified.})$

| Characteristic   | Symbol                           | Value           | Units      |    |
|--|----------------------------------|-----------------|------------|----|
| Drain-Source Voltage   | $V_{DSS}$                        | 40              | V          |    |
| Gate-Source Voltage  |                                  | $V_{GSS}$       | ±20        | V  |
| Continuous Drain Current, V <sub>GS</sub> = 10V (Notes 6, 9) | $T_C = +25$ °C<br>$T_C = +70$ °C | I <sub>D</sub>  | 100<br>100 | А  |
| Pulsed Drain Current (10µs pulse, duty cycle = 1%)           |                                  | I <sub>DM</sub> | 200        | Α  |
| Continuous Body Diode Forward Current (Note 6)               | T <sub>C</sub> = +25°C           | I <sub>S</sub>  | 85         | Α  |
| Avalanche Current, L = 0.1mH                                 |                                  | I <sub>AS</sub> | 48         | Α  |
| Avalanche Energy, L = 0.1mH                                  |                                  | E <sub>AS</sub> | 115        | mJ |

## **Thermal Characteristics**

| Characteristic                                   | Symbol                            | Value       | Units |
|--|-----------------------------------|-------------|-------|
| Total Power Dissipation (Note 5)                 | $P_{D}$                           | 2.3         | W     |
| Thermal Resistance, Junction to Ambient (Note 5) | $R_{\theta JA}$                   | 55          | °C/W  |
| Total Power Dissipation (Note 6)                 | $P_{D}$                           | 104         | W     |
| Thermal Resistance, Junction to Case (Note 6)    | $R_{\theta JC}$                   | 1.2         | °C/W  |
| Operating and Storage Temperature Range          | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C    |

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                             | Symbol              | Min | Тур   | Max  | Unit                                       | Test Condition   |  |
|--|---------------------|-----|-------|------|--|--|--|
| OFF CHARACTERISTICS (Note 7)               |                     |     |       |      |  |  |  |
| Drain-Source Breakdown Voltage             | BV <sub>DSS</sub>   | 40  | _     | _    | V  | $V_{GS} = 0V, I_D = 250\mu A$                                |  |
| Zero Gate Voltage Drain Current            | I <sub>DSS</sub>    | _   | _     | 1    | μΑ   | $V_{DS} = 32V, V_{GS} = 0V$                                  |  |
| Gate-Source Leakage                        | Igss                | _   | _     | ±100 | nA   | $V_{GS} = \pm 20V, V_{DS} = 0V$                              |  |
| ON CHARACTERISTICS (Note 7)                | 3.55                |     | l.    | l .  | l.   | , ==   |  |
| Gate Threshold Voltage                     | V <sub>GS(TH)</sub> | 1   | _     | 3    | V  | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$                         |  |
| Static Drain-Source On-Resistance          |                     | _   | 1.3   | 1.8  | mΩ   | $V_{GS} = 10V, I_D = 25A$                                    |  |
| Static Drain-Source On-Resistance          | R <sub>DS(ON)</sub> | _   | 2     | 3.1  | 11177                                      | $V_{GS} = 4.5V, I_D = 25A$                                   |  |
| Diode Forward Voltage                      | $V_{SD}$            | _   | _     | 1.2  | V  | $V_{GS} = 0V, I_{S} = 20A$                                   |  |
| DYNAMIC CHARACTERISTICS (Note 8)           |                     |     |       |      |  |  |  |
| Input Capacitance                          | C <sub>iss</sub>    | _   | 6771  | _    |  | $V_{DS} = 20V, V_{GS} = 0V,$<br>f = 1MHz                     |  |
| Output Capacitance                         | Coss                | _   | 2165  | _    | pF   |  |  |
| Reverse Transfer Capacitance               | $C_{rss}$           | _   | 176   | _    |  |  |  |
| Gate Resistance                            | Rg                  | _   | 0.85  | _    | Ω  | $V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$                   |  |
| Total Gate Charge (V <sub>GS</sub> = 10V)  | $Q_{g}$             | -   | 116.1 | _    |  | $V_{DD} = 20V, I_D = 25A,$<br>$V_{GS} = 10V$                 |  |
| Total Gate Charge (V <sub>GS</sub> = 4.5V) | $Q_g$               | 1   | 55.2  | _    | nC   |  |  |
| Gate-Source Charge                         | Qgs                 | _   | 20.3  | _    | 110  |  |  |
| Gate-Drain Charge                          | $Q_{gd}$            | _   | 22.7  | _    |  |  |  |
| Turn-On Delay Time                         | t <sub>D(ON)</sub>  | _   | 11.4  | _    |  | $V_{DD} = 20V, V_{GS} = 10V,$ $I_{D} = 25A, R_{G} = 3\Omega$ |  |
| Turn-On Rise Time                          | t <sub>R</sub>      | _   | 22.9  | _    |  |  |  |
| Turn-Off Delay Time                        | t <sub>D(OFF)</sub> | _   | 62.5  | _    | ns   |  |  |
| Turn-Off Fall Time                         | t <sub>F</sub>      | _   | 28    | _    |  |  |  |
| Reverse Recovery Time                      | t <sub>RR</sub>     | _   | 58.6  | _    | ns   | I_ 05A di/dt 100A/us   |  |
| Reverse Recovery Charge                    | Q <sub>RR</sub>     | _   | 107   | _    | nC   I <sub>F</sub> = 25A, di/dt = 100A/µs |  |  |

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

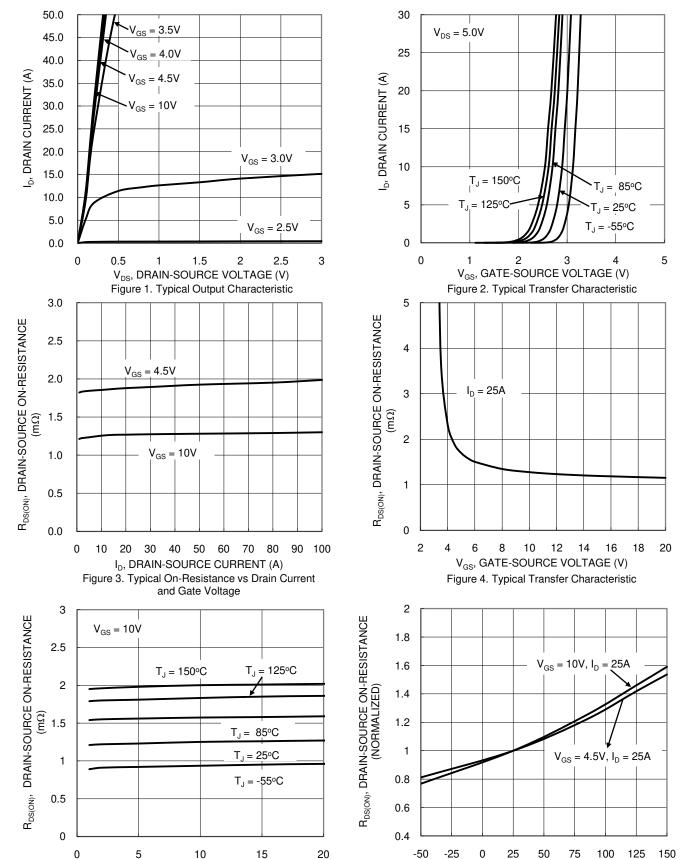
<sup>6.</sup> Thermal resistance from junction to soldering point (on the exposed drain pad).

<sup>7.</sup> Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.

Package limited.







10

I<sub>D</sub>, DRAIN CURRENT (A)

Figure 5. Typical On-Resistance vs Drain Current

and Temperature

15

20

-50

0

25

50

T<sub>J</sub>, JUNCTION TEMPERATURE (°C)

Figure 6. On-Resistance Variation with Temperature

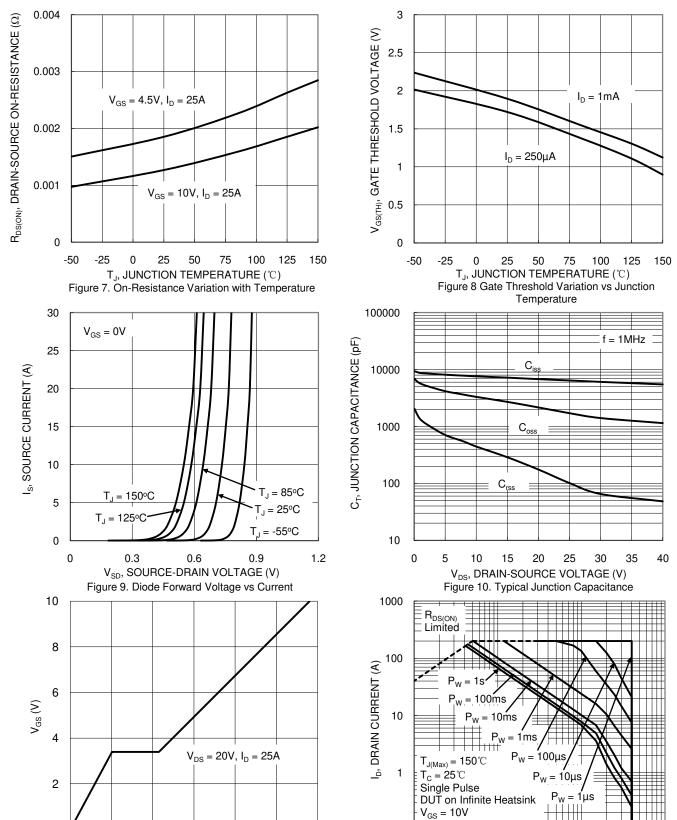
75

100 125 150

0







20

40

60

 $Q_g$  (nC)

Figure 11. Gate Charge

80

100

120

0

0

0.1

0.1

100

10

V<sub>DS</sub>, DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area



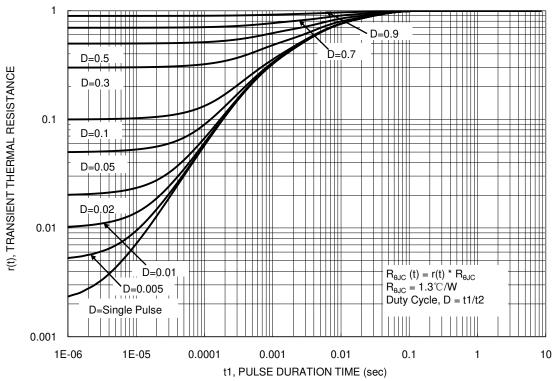


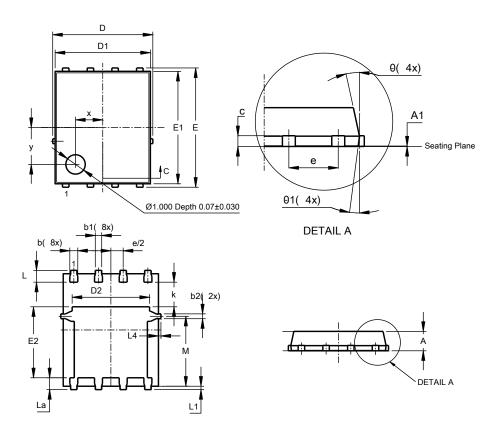
Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

## PowerDI5060-8 (Type K)

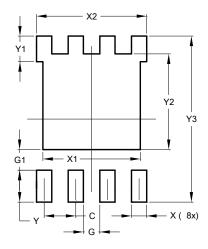


| PowerDI5060-8        |       |         |       |  |  |
|----------------------|-------|---------|-------|--|--|
| (Type K)             |       |         |       |  |  |
| Dim                  | Min   | Max     | Тур   |  |  |
| Α                    | 0.90  | 1.10    | 1.00  |  |  |
| <b>A</b> 1           | 0     | 0.05    | 0.02  |  |  |
| р                    | 0.33  | 0.51    | 0.41  |  |  |
| b1                   | 0.300 | 0.366   | 0.333 |  |  |
| b2                   | 0.20  | 0.35    | 0.25  |  |  |
| С                    | 0.23  | 0.33    | 0.277 |  |  |
| D                    | 5     | .15 BS0 | 2     |  |  |
| D1                   | 4.85  | 4.95    | 4.90  |  |  |
| D2                   | -     | -       | 3.98  |  |  |
| E                    | 6     | .15 BS0 |       |  |  |
| E1                   | 5.75  | 5.85    | 5.80  |  |  |
| E2                   | 3.56  | 3.725   | 3.66  |  |  |
| Е                    | 1     | .27BSC  |       |  |  |
| k                    | -     | -       | 1.27  |  |  |
| ٦                    | 0.51  | 0.71    | 0.61  |  |  |
| La                   | 0.51  | 0.675   | 0.61  |  |  |
| L1                   | 0.05  | 0.20    | 0.175 |  |  |
| L4                   | -     | -       | 0.125 |  |  |
| М                    | 3.50  | 3.71    | 3.605 |  |  |
| Х                    | -     | -       | 1.400 |  |  |
| у                    | -     | -       | 1.900 |  |  |
| θ                    | 10°   | 12°     | 11°   |  |  |
| θ1                   | 6°    | 8°      | 7°    |  |  |
| All Dimensions in mm |       |         |       |  |  |

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

## PowerDI5060-8 (Type K)



| Dimensions | Value<br>(in mm) |  |  |
|------------|------------------|--|--|
| С          | 1.270            |  |  |
| G          | 0.660            |  |  |
| G1         | 0.820            |  |  |
| X          | 0.610            |  |  |
| X1         | 3.910            |  |  |
| X2         | 4.420            |  |  |
| Υ          | 1.270            |  |  |
| Y1         | 1.020            |  |  |
| Y2         | 3.810            |  |  |
| Y3         | 6.610            |  |  |



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